NSN 5961-00-328-1667

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-328-1667 **Inclosure Material:** Metal **Overall Length:** Between 0.205 inches and 0.225 inches Overall Diameter: Between 0.120 inches and 0.130 inches **End Application:** E-2c hawkeye aircraft **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 20.0 breakdown voltage, dc **Current Rating Per Characteristic:** 50.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 800.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Weapon system essential **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Test Data Document:** 99971-7534348 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig:

No

A110a0